

## Main Specifications

(unless otherwise specified, @ $T_c=25^\circ\text{C}$ )

	Part number	<b>MG800FXF2YMS3</b>
	Package	iXPLV
Absolute maximum ratings	Drain-source voltage $V_{DSS}$ (V)	3300
	Gate-source voltage $V_{GSS}$ (V)	+25/-10
	Drain current (DC) $I_D$ (A)	800
	Drain current (pulsed) $I_{DP}$ (A)	1600
	Channel temperature $T_{ch}$ ( $^\circ\text{C}$ )	175
	Isolation voltage $V_{isol}$ (Vrms)	6000
Electrical characteristics	Drain-source voltage on-voltage (sense) $V_{DS(on)sense}$ typ. (V)	@ $V_{GS}=+20\text{V}$ , $I_D=800\text{A}$ 1.6
	Source-drain voltage on-voltage (sense) $V_{SD(on)sense}$ typ. (V)	@ $V_{GS}=+20\text{V}$ , $I_S=800\text{A}$ 1.5
	Source-drain voltage off-voltage (sense) $V_{SD(off)sense}$ typ. (V)	@ $V_{GS}=-6\text{V}$ , $I_S=800\text{A}$ 2.3
	Stray inductance module $L_{SPN}$ typ. (nH)	12
	Turn-on switching loss $E_{on}$ typ. (mJ)	@ $V_{DD}=1800\text{V}$ , $I_D=800\text{A}$ , $T_{ch}=150^\circ\text{C}$ 250
	Turn-off switching loss $E_{off}$ typ. (mJ)	@ $V_{DD}=1800\text{V}$ , $I_D=800\text{A}$ , $T_{ch}=150^\circ\text{C}$ 240